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- 1. A microphone structure comprising a microphone capsule (200; 300), which has at least first and second output contact, and within said microphone capsule
- means for converting changes in air pressure to an electrical signal,
- 5 preamplifier (Q2; Q3) having first/and second output conductor and
 - a first capacitor (C21; C31) connected between said output conductors of the preamplifier, **characterized** in that it further comprises at least one electro-static discharge protector (VDR2; ZD) connected between said output contacts of microphone capsule and, within the microphone capsule, a first impedance (R21; R31) in series between said first output conductor and said first output contact.
 - 2. A microphone structure according to claim 1, **characterized** in that said electro-static discharge protector is within the microphone capsule.
 - 3. A microphone structure according to claim 1, characterized in that said electro-static discharge protector is outside the microphone capsule, close by this.
- 4. A microphone structure according to claim 1, **characterized** in that it further comprises at least second impedance (Z) in series with said first impedance and at least second capacitor (C33).
 - 5. A microphone structure according to claim 4, **characterized** in that at least one of said series impedances is resistive.
- 20 6. A microphone structure according to claim 4, characterized in that at least one of said series impedances is inductive.
 - 7. A microphone structure according to claim 4, **characterized** in that said capacitors and structure parts having series impedance form a ladder network.
- 8. A microphone structure according to claims 2 and 4; characterized in that the preamplifier, electro-static discharge protector, said series structure parts and said capacitors are on the same circuit board (41).
 - 9. A microphone structure according to claim 4, **characterized** in that at least some of said electronic structure parts are inside the same integrated circuit (IC).
- 10. A microphone structure according to claim 1, **characterized** in that the electro-static discharge protector is a varistor (VDR2).

- 11. A microphone structure according to claim 1, **characterized** in that the electro-static discharge protector is a semiconductor (ZD).
- 12. A microphone structure according to claim 1, characterized in that the electro-static discharge protector is a polymer component.
- 5 13. A microphone structure according to claim 1, **characterized** in that the electro-static discharge protector is a feed-through component (FTC).
 - 14. A microphone structure according to claim 1 having at least two electro-static discharge protectors, **characterized** in that electro-static discharge protectors form one of following connections: parallel, series, star.